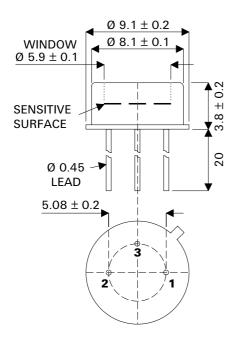


SMP525G-FK

MECHANICAL DATA

Dimensions in mm.



TO-39 Package

Pin 1 – Anode Pin 2 – Cathode

Pin 3 - Case

P.I.N. PHOTODIODE

FEATURES

- ASYMMETRIC VIEWING ANGLES
- WIDEST SPECTRAL RESPONSE
- ENHANCED UV SENSITIVITY
- PHOTODIODE ISOLATED FROM PACKAGE
- EXCELLENT LINEARITY
- LOW NOISE
- LOW LEAKAGE CURRENT
- LOW CAPACITANCE
- INTEGRAL OPTICAL FILTER OPTION note 1
- TO39 HERMETIC METAL CAN PACKAGE
- EMI SCREENING MESH AVAILABLE

Note 1 Contact Semelab Plc for filter options DESCRIPTION

The SMP525G-FK is a Silicon P.I.N. photodiode incorporated in a hermetic metal can package. The package window has greater ultra-violet light transmission, thus extending the useful spectral range of the device. The electrical terminations are via two leads of diameter 0.018" on pitch centre diameter of 0.2". The photodiode is electrically isolated from the package, which has a separate earth lead.

The photodiode active area provides asymmetric viewing angles in two orthogonal directions. The photodiode structure has been optimised for high sensitivity, asymmetric light measurement applications across the infra-red to ultra-violet spectrum. Inclusion of a suitable optical filter into the package can produce a device that responds only to ultra-violet light. The metal can, isolated photodiode and optional screening mesh ensure a rugged device with a high degree of immunity to conducted and radiated electrical interference.

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C unless otherwise stated)

Operating temperature range	-40°C to +70°C
Storage temperature range	-45°C to +80°C
Temperature coefficient of responsively	0.35% per °C
Temperature coefficient of dark current	x2 per 8°C rise
Reverse breakdown voltage	60V

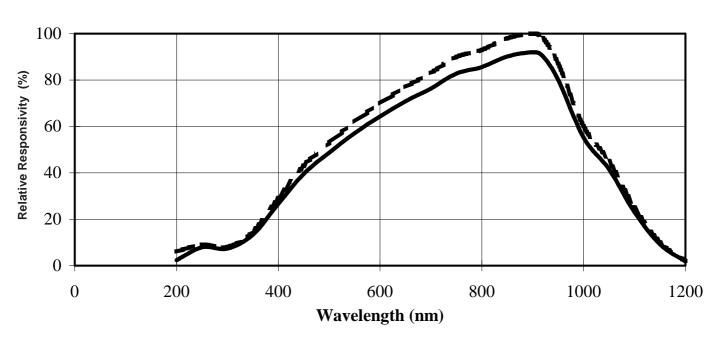


SMP525G-FK

CHARACTERISTICS (T_{amb}=25°C unless otherwise stated)

Characteristic	Test Conditions.		Min.	Тур.	Max.	Units	
Responsively	λ at 900nm		0.45	0.55		A/W	
Active Area				2.05		mm²	
Dark Current	E = 0 Dark	1V Reverse		0.25	4	nA	
	E = 0 Dark	10V Reverse		4	10		
Breakdown Voltage	E = 0 Dark	10µA Reverse	60	80		V	
Capacitance	E = 0 Dark	0V Reverse		45		pF	
	E = 0 Dark	20V Reverse		6		Pi	
Rise Time	30V Reverse					ns	
	50Ω						
NEP	900nm				0.45	W/√Hz	

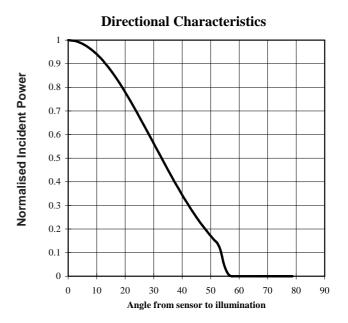
Spectral Response





SMP525G-FK

Directional Characteristics 1 0.9 0.8 0.8 0.7 0.6 0.6 0.5 0.4 0.3 0.2 0.1 0



Directional characteristics

40

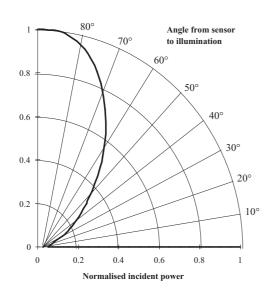
Angle from sensor to illumination

50

90

30

10



Directional characteristics

